# Nch 600V 30A Power MOSFET

| V <sub>DSS</sub>           | 600V   |
|----------------------------|--------|
| R <sub>DS(on)</sub> (Max.) | 0.130Ω |
| I <sub>D</sub>             | ±30A   |
| P <sub>D</sub>             | 305W   |

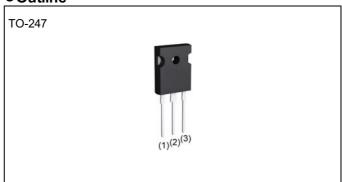
### Features

- 1) Low on-resistance
- 2) Ultra fast switching speed
- 3) Parallel use is easy
- 4) Pb-free plating; RoHS compliant

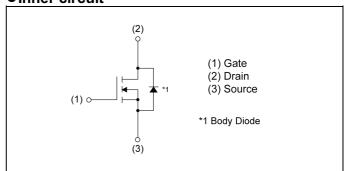
# Application

Switching

### Outline



# •Inner circuit



Packaging specifications

| Packing        | Tube      |
|----------------|-----------|
| Packing code   | C13       |
| Marking        | R6030ENZ4 |
| Quantity (pcs) | 600       |

# ullet Absolute maximum ratings (T<sub>a</sub> = 25°C ,unless otherwise specified)

| Parameter  | Symbol             | Value              | Unit        |    |
|--|--------------------|--------------------|-------------|----|
| Drain - Source voltage                           |                    | V <sub>DSS</sub>   | 600         | V  |
| Continuous drain current (T <sub>c</sub> = 25°C) |                    | I <sub>D</sub> *1  | ±30         | Α  |
| Pulsed drain current                             | I <sub>DP</sub> *2 | ±80                | Α           |    |
| static   |                    | V                  | ±20         | V  |
| Gate - Source voltage                            | AC(f>1Hz)          | V <sub>GSS</sub>   | ±30         | V  |
| Avalanche current, single pulse                  |                    | I <sub>AS</sub>    | 5.2         | Α  |
| Avalanche energy, single pulse                   |                    | E <sub>AS</sub> *3 | 636         | mJ |
| Power dissipation (T <sub>c</sub> = 25°C)        | P <sub>D</sub>     | 305                | W           |    |
| Junction temperature                             | T <sub>j</sub>     | 150                | °C          |    |
| Operating junction and storage tempera           | ature range        | T <sub>stg</sub>   | -55 to +150 | °C |

### ●Thermal resistance

| Downwortow                                   | O                    | Values |      |      | 1.1  |
|--|----------------------|--------|------|------|------|
| Parameter                                    | Symbol               | Min.   | Тур. | Max. | Unit |
| Thermal resistance, junction - case          | R <sub>thJC</sub> *4 | -      | -    | 0.41 | °C/W |
| Thermal resistance, junction - ambient       | R <sub>thJA</sub>    | -      | -    | 30   | °C/W |
| Soldering temperature, wavesoldering for 10s | T <sub>sold</sub>    | -      | -    | 265  | °C   |

# • Electrical characteristics $(T_a = 25^{\circ}C)$

| Darameter                                   | Cumb al                                | Conditions                                    | Values |       |       | Unit  |
|---|--|---|--------|-------|-------|-------|
| Parameter                                   | Symbol                                 | Conditions                                    | Min.   | Тур.  | Max.  | Offic |
| Drain - Source breakdown voltage            | $V_{(BR)DSS}$ $V_{GS} = 0V, I_D = 1mA$ |   | 600    | -     | -     | V     |
|   |  | V <sub>DS</sub> = 600V, V <sub>GS</sub> = 0V  |        |       |       |       |
| Zero gate voltage drain current             | I <sub>DSS</sub>                       | $T_j = 25^{\circ}C$                           | -      | -     | 100   | μΑ    |
| aram canoni                                 |  | $T_j = 125^{\circ}C$                          | -      | -     | 1000  |       |
| Gate - Source leakage current               | I <sub>GSS</sub>                       | V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0V  | -      | -     | ±100  | nA    |
| Gate threshold voltage                      | $V_{GS(th)}$                           | $V_{DS}$ = 10V, $I_D$ = 1mA                   | 2.0    | -     | 4.0   | ٧     |
|   |  | V <sub>GS</sub> = 10V, I <sub>D</sub> = 14.5A |        |       |       |       |
| Static drain - source on - state resistance | R <sub>DS(on)</sub> *5                 | $T_j = 25^{\circ}C$                           | -      | 0.115 | 0.130 | Ω     |
|   |  | $T_j = 125^{\circ}C$                          | -      | 0.255 | -     |       |
| Gate resistance                             | $R_{G}$                                | f = 1MHz, open drain                          | -      | 3.6   | -     | Ω     |

# ● Electrical characteristics (T<sub>a</sub> = 25°C)

| Davamatar                    | Cymahal                  | Conditions                            | Values |      |      | Unit |
|------------------------------|--------------------------|---------------------------------------|--------|------|------|------|
| Parameter                    | Symbol                   | Conditions                            | Min.   | Тур. | Max. | Unit |
| Input capacitance            | C <sub>iss</sub>         | V <sub>GS</sub> = 0V                  | -      | 2100 | -    |      |
| Output capacitance           | C <sub>oss</sub>         | V <sub>DS</sub> = 25V                 | -      | 1900 | -    | pF   |
| Reverse transfer capacitance | C <sub>rss</sub>         | f = 1MHz                              | -      | 190  | -    |      |
| Turn - on delay time         | t <sub>d(on)</sub> *5    | $V_{DD} \simeq 300V$ , $V_{GS} = 10V$ | -      | 40   | -    |      |
| Rise time                    | t <sub>r</sub> *5        | I <sub>D</sub> = 15A                  | -      | 55   | -    |      |
| Turn - off delay time        | t <sub>d(off)</sub> *5   | $R_L \simeq 20\Omega$                 | -      | 190  | -    | ns   |
| Fall time                    | <b>t</b> <sub>f</sub> *5 | $R_G = 10\Omega$                      | -      | 60   | -    |      |

# ●Gate charge characteristics (T<sub>a</sub> = 25°C)

| Darameter            | Complete al            | Conditions                                   | Values |      |      | Linit |
|----------------------|------------------------|--|--------|------|------|-------|
| Parameter            | Symbol                 | ymbol Conditions                             |        | Тур. | Max. | Unit  |
| Total gate charge    | $Q_g^{*5}$             | V <sub>DD</sub> ≈ 300V                       | -      | 85   | -    |       |
| Gate - Source charge | Q <sub>gs</sub> *5     | I <sub>D</sub> = 30A                         | -      | 15   | -    | nC    |
| Gate - Drain charge  | Q <sub>gd</sub> *5     | V <sub>GS</sub> = 10V                        | -      | 45   | -    |       |
| Gate plateau voltage | V <sub>(plateau)</sub> | V <sub>DD</sub> ≈ 300V, I <sub>D</sub> = 30A | -      | 6.5  | -    | V     |

<sup>\*1</sup> Limited only by maximum channel temperature allowed.

<sup>\*2</sup> Pw ≤ 10µs, Duty cycle ≤ 1%

<sup>\*3</sup> L $\doteqdot$ 50mH, V<sub>DD</sub>=50V, R<sub>G</sub>=25 $\Omega$ , Starting T<sub>j</sub>=25°C

<sup>\*4</sup> T<sub>C</sub>=25°C

<sup>\*5</sup> Pulsed

# ●Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

| Parameter                     | Cymbol                    | Conditions                                     | Values |      |      | Unit  |  |
|-------------------------------|---------------------------|--|--------|------|------|-------|--|
| - Farameter                   | Symbol                    | Conditions                                     | Min.   | Тур. | Max. | Offic |  |
| Source current                | I <sub>S</sub> *1         | T - 25°C                                       | 1      | -    | 30   | Α     |  |
| Pulsed source current         | I <sub>SP</sub> *2        | T <sub>C</sub> = 25°C                          | 1      | -    | 80   | Α     |  |
| Source-Drain voltage          | V <sub>SD</sub> *5        | $V_{GS} = 0V, I_{S} = 30A$                     | -      | -    | 1.5  | ٧     |  |
| Reverse recovery time         | <b>t</b> <sub>rr</sub> *5 |  | -      | 660  | -    | ns    |  |
| Reverse recovery charge       | Q <sub>rr</sub> *5        | $Q_{rr}^{*5}$ $I_S = 30A$ $di/dt = 100A/\mu s$ |        | 15   | -    | μC    |  |
| Peak reverse recovery current | <sub>rr</sub> *5          |  | -      | 45   | -    | А     |  |

Fig.1 Power Dissipation Derating Curve

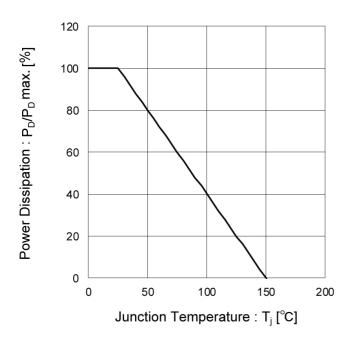


Fig.2 Drain Current Derating Curve

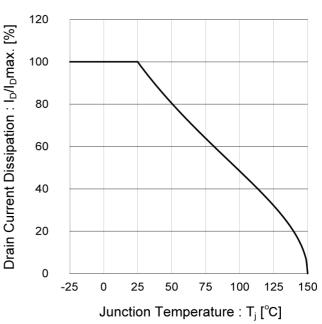


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

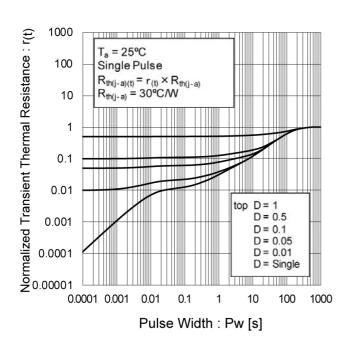
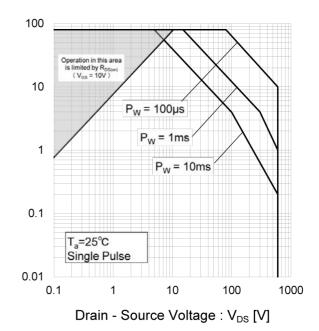


Fig.4 Maximum Safe Operating Area



Drain Current : I<sub>D</sub> [A]

Fig.5 Avalanche Energy Derating
Curve vs. Junction Temperature

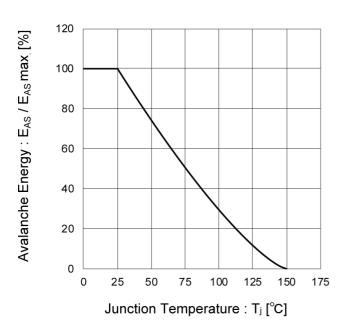


Fig.6 Normalized Breakdown Voltage vs. Junction Temperature

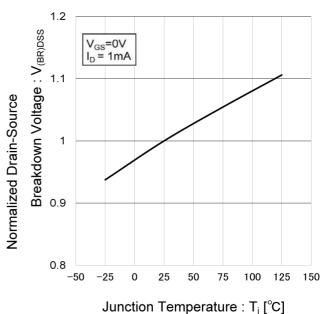
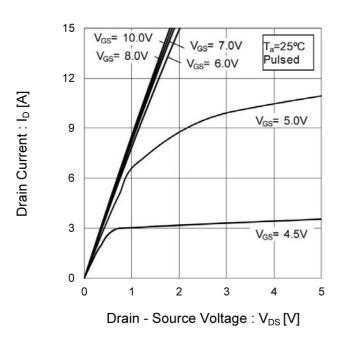


Fig.7 Typical Output Characteristics(I)



Drain Current : I<sub>D</sub> [A]

30 V<sub>GS</sub>= 6.0V T<sub>a</sub>=25℃ Pulsed V<sub>GS</sub>= 10.0V 25 V<sub>GS</sub>= 8.0V V<sub>GS</sub>= 7.0V 20  $V_{GS} = 5.0V$ 15 10 5 V<sub>GS</sub>= 4.5V 0 10 20 0 30 50

Drain - Source Voltage: V<sub>DS</sub>[V]

Fig.8 Typical Output Characteristics(II)



Fig.9 Typical Transfer Characteristics

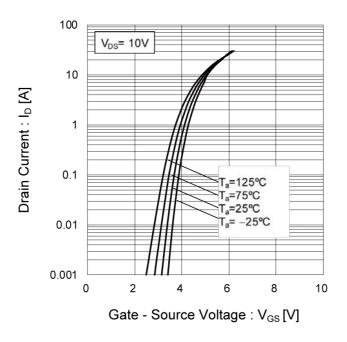


Fig.10 Gate Threshold Voltage vs. Junction Temperature

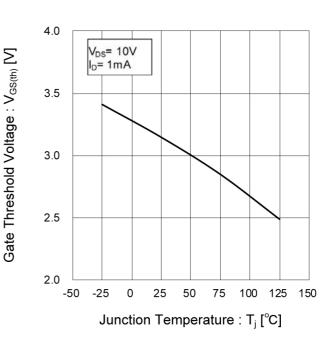


Fig.11 Static Drain - Source On - State Resistance vs. Drain Current

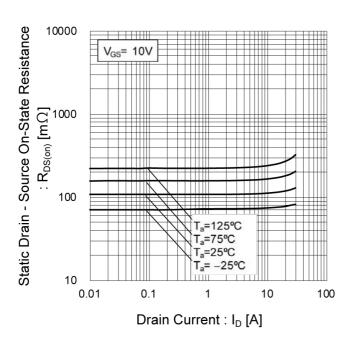


Fig.12 Static Drain - Source On - State Resistance vs. Gate - Source Voltage

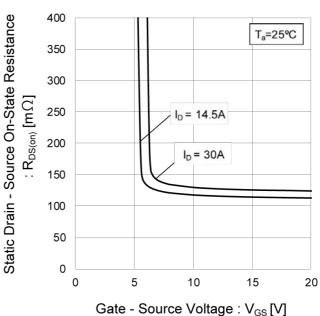


Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature

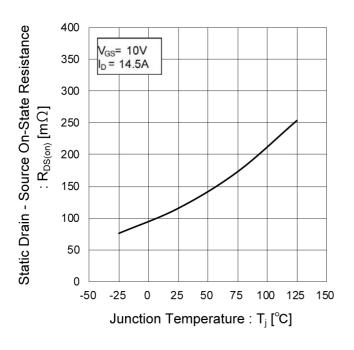


Fig.14 Typical Capacitance vs.
Drain - Source Voltage

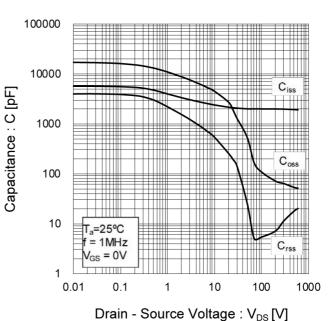


Fig.15 Switching Characteristics

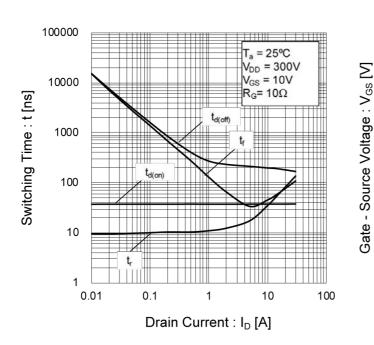


Fig.16 Typical Gate Charge

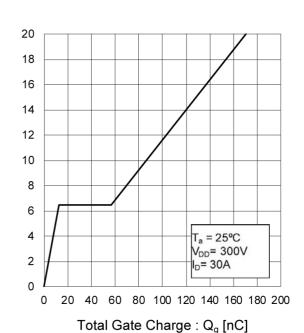


Fig.17 Source Current vs. Source - Drain Voltage

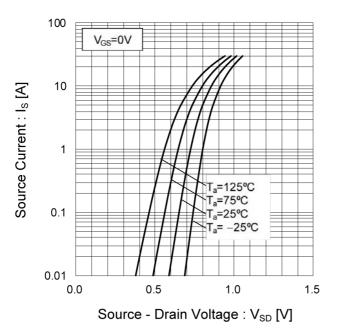
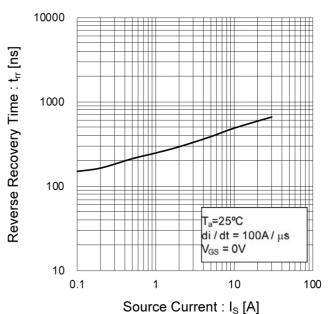


Fig.18 Reverse Recovery Time vs. Source Current



### Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

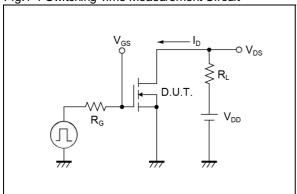


Fig.2-1 Gate Charge Measurement Circuit

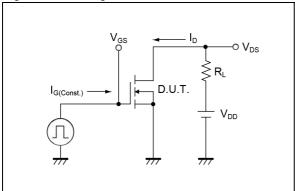


Fig.3-1 Avalanche Measurement Circuit

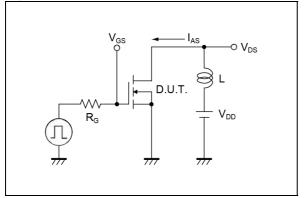


Fig.4-1 trr Measurement Circuit

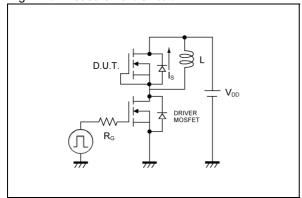


Fig.1-2 Switching Waveforms

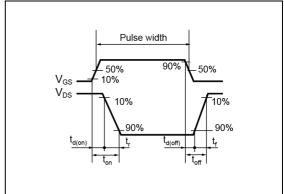


Fig.2-2 Gate Charge Waveform

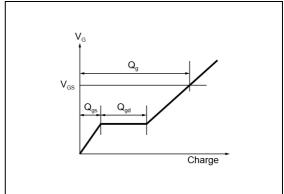


Fig.3-2 Avalanche Waveform

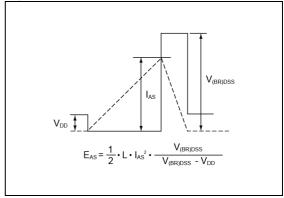
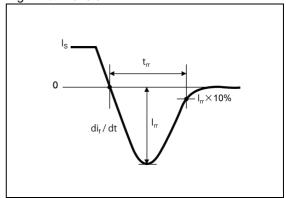
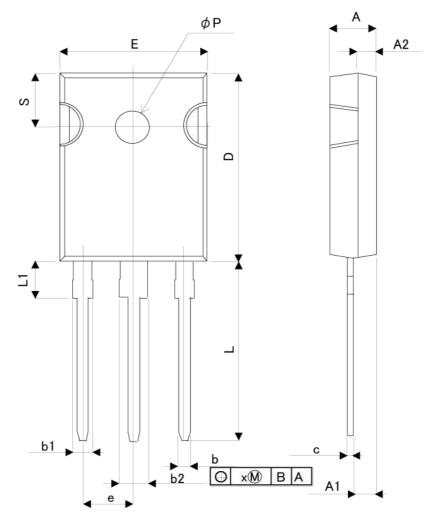


Fig.4-2 trr Waveform



# Dimensions

TO-247



| DIM | MILIME | ETERS | INCH  | HES   |
|-----|--------|-------|-------|-------|
| DIM | MIN    | MAX   | MIN   | MAX   |
| Α   | 4.82   | 5.22  | 0.190 | 0.206 |
| A1  | 2.11   | 2.71  | 0.083 | 0.107 |
| A2  | 1.80   | 2.20  | 0.071 | 0.087 |
| b   | 1.00   | 1.40  | 0.039 | 0.055 |
| b1  | 1.80   | 2.20  | 0.071 | 0.087 |
| b2  | 2.80   | 3.20  | 0.110 | 0.126 |
| С   | 0.45   | 0.75  | 0.018 | 0.030 |
| D   | 20.65  | 21.25 | 0.813 | 0.837 |
| E   | 15.64  | 16.24 | 0.616 | 0.639 |
| е   | 5.4    | 14    | 0.2   | 14    |
| L   | 19.77  | 20.37 | 0.778 | 0.802 |
| L1  | 4.09   | 4.29  | 0.161 | 0.169 |
| Р   | 3.51   | 3.71  | 0.138 | 0.146 |
| S   | 5.97   | 6.37  | 0.235 | 0.251 |

Dimension in mm/inches

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| JÁPAN   | USA    | EU         | CHINA     |
|---------|--------|------------|-----------|
| CLASSⅢ  | СГУССШ | CLASS II b | CL ACCIII |
| CLASSIV | CLASSⅢ | CLASSⅢ     | CLASSⅢ    |

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  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
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  - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
  may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
  exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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